

RQ3L070BG

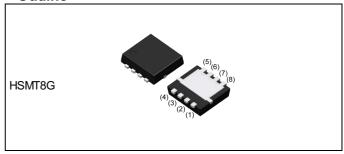
Nch 60V 20A Power MOSFET

$V_{ t DSS}$	60V
R _{DS(on)} (Max.)	24.7mΩ
l _D	±20A
P_D	15W

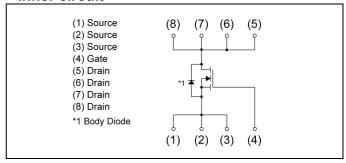
Features

- 1) Low on resistance
- 2) Small Surface Mount Package
- 3) Pb-free plating; RoHS compliant

Outline



●Inner circuit



Packaging specifications

- i dekaging epeemediene				
	Packing	Embossed Tape		
	Reel size (mm)	330		
Туре	Tape width (mm)	12		
	Quantity (pcs)	3000		
	Taping code	TB1		
	Marking	L070BG		

Application

Primary side switch

Moter drives

DC/DC converter

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Paramete	Symbol	Value	Unit	
Drain - Source voltage		V _{DSS}	60	V
Oti	T _c = 25°C	I _D *1	±20	Α
Continuous drain current	T _a = 25°C	I _D	±7.0	Α
Pulsed drain current		I _{DP} *2	±28	А
Gate - Source voltage		V_{GSS}	±20	V
Avalanche current, single pulse		I _{AS} *3	7.0	Α
Avalanche energy, single pulse		E _{AS} *3	2.5	mJ
Dower discipation		P _D *1	15	W
Power dissipation		P _D *4	2.0	W
Junction temperature		T _j	150	°C
Operating junction and storage temperature range		T _{stg}	-55 to +150	°C

●Thermal resistance

Doromotor	Curah al	Values			1.1:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *1	-	-	8.3	°C/W
Thermal resistance, junction - ambient	R _{thJA} *4	-	-	62.5	°C/W

● Electrical characteristics (T_a = 25°C)

Davanastan	Cymaele ed	Symbol Conditions		Values		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	60	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	$\frac{\Delta V_{(BR)DSS}}{\Delta T_i} I_D = 1 \text{mA}$ referenced to 25°C		38.9	-	mV/°C
Zero gate voltage drain current	I _{DSS}	V _{DS} = 60V, V _{GS} = 0V	-	-	1	μA
Gate - Source leakage current	I _{GSS}	I_{GSS} $V_{GS} = \pm 20V, V_{DS} = 0V$		1	±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = 1mA$		-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_{j}}$			-4.7	-	mV/°C
Static drain - source	D *5	$V_{GS} = 10V, I_D = 7.0A$	-	19.8	24.7	
on - state resistance	R _{DS(on)} *5	V _{GS} = 4.5V, I _D = 7.0A	-	27.6	37.3	mΩ
Gate resistance	R_G	-	-	2.2	-	Ω
Forward Transfer Admittance	Y _{fs} *5	V _{DS} = 5V, I _D = 7.0A	2.5	-	-	S

^{*1}T_c =25°C, Limited only by maximum temperature allowed.



^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \simeq 0.1mH, V_{DD} = 30V, R_G = 25 Ω , Starting T_j = 25 $^{\circ}$ C Fig.3-1,3-2

^{*4} Mounted on a Cu board (40×40×0.8mm)

^{*5} Pulsed

● Electrical characteristics (T_a = 25°C)

Davanastan	Condition	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	-	460	-	
Output capacitance	C _{oss}	V _{DS} = 30V	-	180	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	17	-	
Turn - on delay time	t _{d(on)} *5	$V_{DD} \simeq 30V, V_{GS} = 10V$	-	8.7	-	
Rise time	t _r *5	I _D = 3.5A	-	5.6	-	
Turn - off delay time	t _{d(off)} *5	R _L ≃ 8.57Ω	-	21.0	-	ns
Fall time	t _f *5	$R_G = 10\Omega$	-	4.4	-	

• Gate charge characteristics $(T_a = 25^{\circ}C)$

Darameter	Cymahal	Conditions		Values			1.1-24	
Parameter	Symbol			Min.	Тур.	Max.	Unit	
Total gate above	O *5	O *5	Vo	V _{GS} = 10V	-	7.6	-	
Total gate charge	Q_g	Q_g^{*5} $V_{DD} \simeq 30V$		-	3.9	-	5 C	
Gate - Source charge	Q _{gs} *5	$I_{D} = 7.0A$	V _{GS} = 4.5V	-	1.7	-	nC	
Gate - Drain charge	Q _{gd} *5			-	1.2	-		

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol Conditions		Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I _S	T _a = 25°C	1	-	1.67	Α
Pulse forward current	I _{SP} *2	1 _a - 25 C	-	-	28	Α
Forward voltage	V _{SD} *5	V _{GS} = 0V, I _S = 1.67A	-	-	1.2	V
Reverse recovery time	t _{rr} *5	I _S = 7.0A, V _{GS} =0V	-	25	-	ns
Reverse recovery charge	Q _{rr} *5	di/dt = 100A/μs	-	22	-	nC

Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

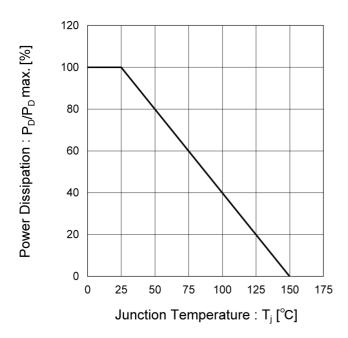
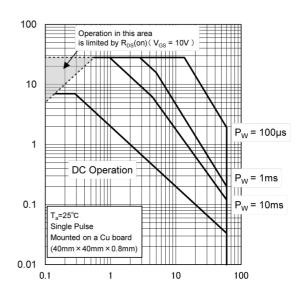


Fig.2 Maximum Safe Operating Area



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

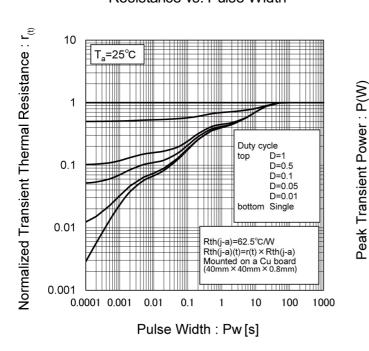
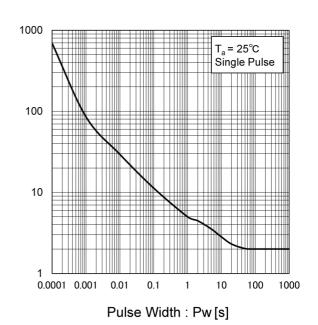


Fig.4 Single Pulse Maximum Power Dissipation



Drain Current : I_D [A]

• Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

7
6
V_{GS}= 10V
5
V_{GS}= 4.5V

T_a=25°C
Pulsed

V_{GS}= 3.5V
3

V_{GS}= 3.5V

T_a=25°C
Pulsed

V_{GS}= 3.0V

T_a=25°C
Pulsed

V_{GS}= 3.0V

T_a=25°C
Pulsed

V_{GS}= 3.0V

T_a=25°C
Pulsed

Fig.6 Typical Output Characteristics(II)

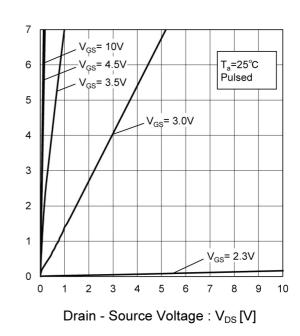


Fig.7 Normalized Breakdown Voltage vs. Junction Temperature

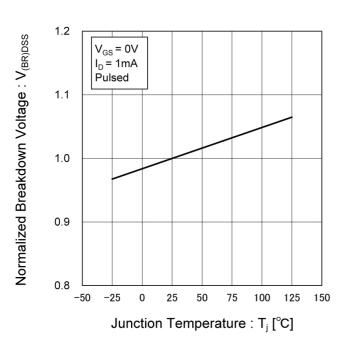
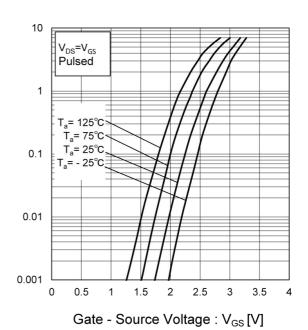


Fig.8 Typical Transfer Characteristics



Drain Current : I_D [A]

Drain Current : I_D [A]

• Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs.
Junction Temperature

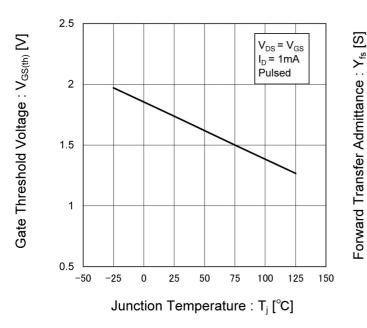


Fig.10 Forward Transfer Admittance vs.
Drain Current

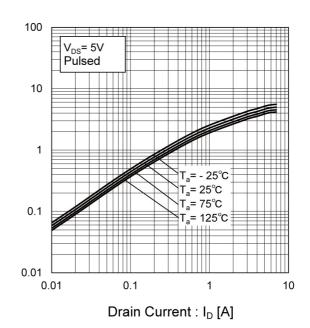


Fig.11 Drain Current Derating Curve

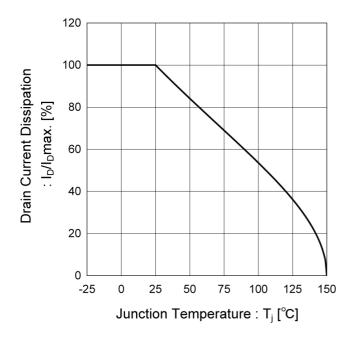
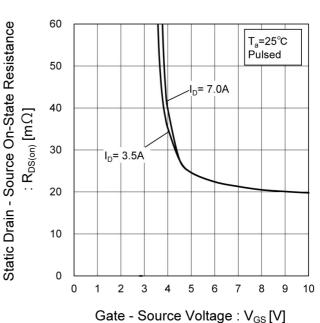


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



• Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

Static Drain - Source On-State Resistance 35 V_{GS} = 10V Pulsed 30 $R_{DS(on)}$ [m Ω] 25 $I_{D} = 7.0A$ 20 15 10 -50 -25 0 25 75 100 125 150 Junction Temperature : T_i [°C]

Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current (I)

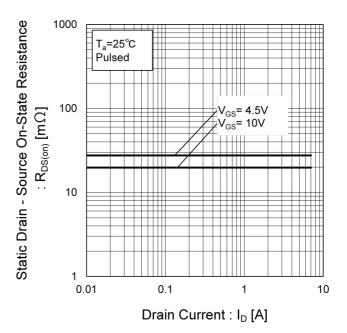


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

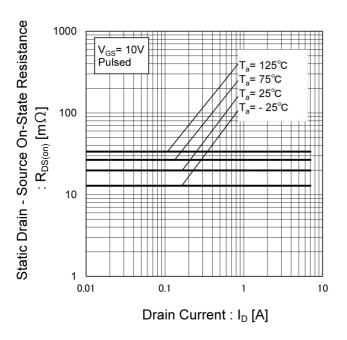
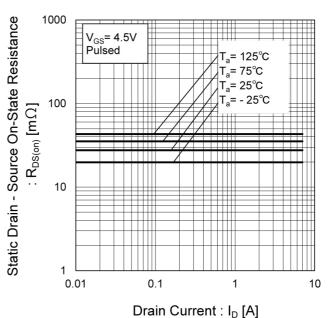


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)



• Electrical characteristic curves

Fig.17 Typical Capacitances vs.

Drain - Source Voltage

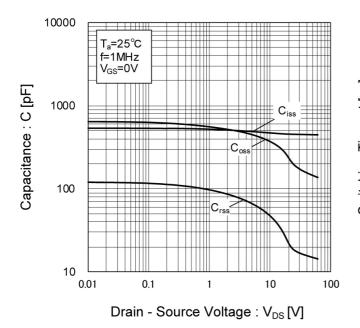


Fig.18 Switching Characteristics

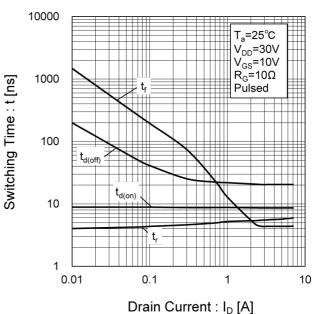


Fig.19 Typical Gate Charge

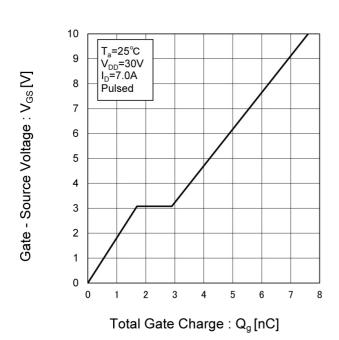
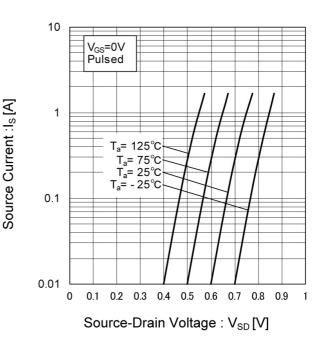


Fig.20 Source Current vs.

Source Drain Voltage



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

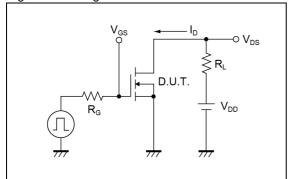


Fig.1-2 Switching Waveforms

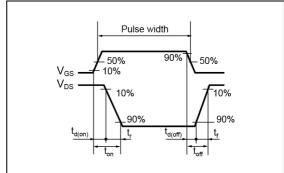


Fig.2-1 Gate Charge Measurement Circuit

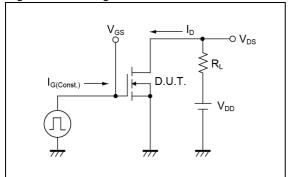


Fig.2-2 Gate Charge Waveform

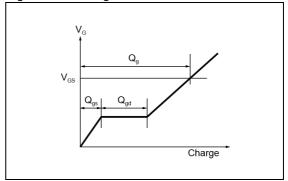


Fig.3-1 Avalanche Measurement Circuit

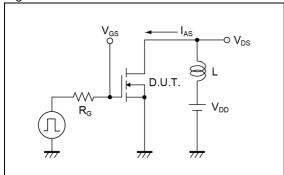
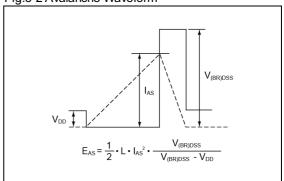


Fig.3-2 Avalanche Waveform



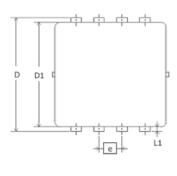
Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

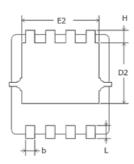
Dimensions

HSMT8 (TB1)

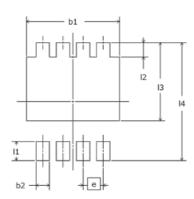
(3.3x3.3)











Refarenced footprint dimensions

DIM	Milimeters		Inc	hes	
DIM	Min.	Max.	Min.	Max.	
Α	0.70	0.80	0.028	0.031	
b	0.25	0.35	0.010	0.014	
С	0.10	0.25	0.004	0.010	
D	3.25	3.45	0.128	0.136	
D1	3.00	3.20	0.118	0.126	
D2	1.78	1.98	0.070	0.078	
Е	3.20	3.40	0.126	0.134	
E1	3.00	3.20	0.118	0.126	
E2	2.39	2.59	0.094	0.102	
е	0.0	65	0.0	26	
Н	0.30	0.50	0.012	0.020	
L	0.30	0.50	0.012	0.020	
L1	0.	13	0.005		

DIM	Milimeters	Inches
DIM	Nom.	Nom.
- 11	0.60	0.024
12	0.45	0.018
13	2.45	0.096
14	3.70	0.146
b1	3.00	0.118
b2	0.43	0.017

Dimension in mm/inches



Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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JÁPAN	USA	EU	CHINA
CLASSⅢ	ОГУООШ	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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